

Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed..., with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).











All data are given with a $\mathbf{R}_1 = 10 \text{ k}\Omega$

ata		
Primary current measuring range	Type	RoHS since date code
± 150	HAIS 50-P, HAIS 50-TP 1)	45231, 46272
± 300	HAIS 100-P, HAIS 100-TP 1)	45231, 46012
± 450	HAIS 150-P	46172
± 600	HAIS 200-P	45231
± 600	HAIS 400-P	47096
	Primary current measuring range $I_{PM} (A)$ ± 150 ± 300 ± 450 ± 600	Primary current Type measuring range I _{PM} (A) ± 150

V _{OUT}	Output voltage (Analog) @ Ip	V _{OE} ± (0.625⋅ I _P	/I _{PN}) V
GTH	Theoretical sensitivity	0.625	V/I _{PN}
V _{REF}	Reference voltage 2) - Output voltage	2.5 ± 0.025	V
114	V _{REF} Output impedance	typ. 200	Ω
	V _{REF} Load impedance	≥ 200	$k\Omega$
R,	Load resistance	≥ 2	$k\Omega$
R _{OUT}	Output internal resistance	< 5	Ω
	Capacitive loading (± 20 %)	=4.7	nF
C _L	Supply voltage (± 5 %)3)	100° 5 0M.	V
Ic	Current consumption @ V _C = 5 V	19	mΑ
-			

*C	Current consumption & V _C = 5 V		1117 (
Ac	ccuracy - Dynamic performance data		
X	Accuracy 4 @ I _{PN} , T _A = 25°C	≤±1	% of I _{PN}
$\varepsilon_{\scriptscriptstyle \rm I}$	Linearity error 0 I _{PM}	≤ ± 0.5	% of I _{PN}
TCV	Temperature coefficient of V _{OE}	≤ ± 0.3	mV/K
	F Temperature coefficient of V _{REF.} +25°C+85°C	\leq ± 0.01	%/K
IX.	-40°C+25°C	\leq ± 0.015	%/K
TCV _{OF} /V	Temperature coefficient of V _{OE} / V _{REF}	≤ ± 0.2	mV/K
TCG	Temperature coefficient of G	$\leq \pm 0.05\%$ (of reading/K
V_{OE}			25 V
V _{OM}	Magnetic offset voltage @ $I_p = 0$,	- XIVI.100 x	
OW	after an overload of I _{PM} HAIS 50-(T)P	$< \pm 0.5$	% of I _{PN}
	HAIS 100-(T)P400-P	$< \pm 0.4$	% of I _{PN}
t _{ra}	Reaction time @ 10 % of I _{PN}	< 3	μs
t,	Response time to 90 % of I _{PN} step	< 5	μs
di/dt	di/dt accurately followed	> 100	A/µs
\mathbf{V}_{no}	Output voltage noise (DC10 kHz)	< 15	mVpp
110	(DC 1 MHz)	< 40	mVpp
BW	Frequency bandwidth (- 3 dB) 5)	DC 50	kHz

Notes: 1)-TP version is equipped with a primary bus bar.

- $^{2)}$ It is possible to overdrive \mathbf{V}_{REF} with an external reference voltage between 1.5 2.8 V providing its ability to sink or source approximately 5 mA.
- $^{3)}$ Maximum supply voltage (not operating) < 6.5 V
- 4) Excluding Offset and Magnetic offset voltage.
- ⁵⁾ Small signal only to avoid excessive heatings of the magnetic core.

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$I_{PN} = 50 ... 400 A$





Features

- · Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation test voltage 2500V
- Low power consumption
- Single power supply +5V
- Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

Advantages

- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V_{REF}. IN/OUT

Applications

- · AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

Industrial



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General data

T _A	Ambient operating temperature	- 40 + 85	°C
T	Ambient storage temperature	- 40 + 85	°C
m	Mass (in brackets : TP version)	20 (30)	g
	Standards	EN 50178: 199	7

Isolation characteristics

- WWW.100Y.COM. Rated isolation voltage rms with EN50178, IEC61010-1 standards at following conditions
 - Over voltage category III
 - Pollution degree 2
 - Heterogeneous field

	EN50178	IEC61010-1	100	
Single insulation	1000V	1000V	100	
Reinforced insulation	600V	300V		
TW	1	001.0	100	
V _d Rms voltage for <i>i</i>	AC isolation test, 50 Hz	z, 1 min 2.5	kV	
V Partial discharge	avtination valtage rms	@ 10nC		

V _d	Rms voltage for AC isolation test, 50 Hz, 1 min	2.5	kV
V	Partial discharge extinction voltage rms @ 10pC		
111111	HAIS 50400-P	> 1	kV
	HAIS 50100-TP	> 1.4	kV
V _w	Impulse withstand voltage 1.2/50 µs	8	kV
dCp	Creepage distance	> 8	mm
dCl	Clearance distance	> 8	mm www.
CTI	Comparative tracking index (Group I)	> 600	
	If insulated cable is used for the primary circuit, the voltage category could be improved with the following	table :	
	Cable insulation (primary) Category HAR 03 450V CAT III	ONY.COL	

550V CAT III

650V CAT III

Safety



HAR 05

HAR 07

This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

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Dimensions HAIS 50..400-P and HAIS 50..100-TP (in mm)

